

■ Features

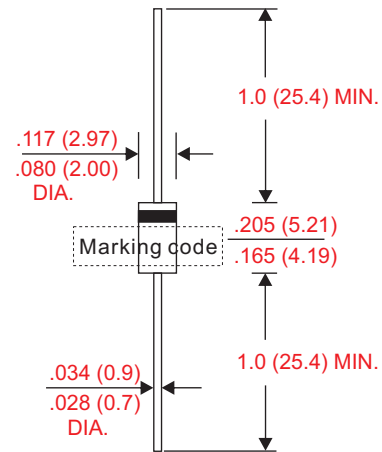
- Axial lead type devices for through hole design.
- High current capability.
- Ultrafast recovery time for switching mode application.
- High surge current capability.
- Glass passivated chip junction.
- Suffix "G" indicates Halogen free parts, ex. UF1005G
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

■ Mechanical data

- Epoxy: UL94-V0 rated flame retardant
- Case : Molded plastic, DO-204AL / DO-41
- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guaranteed
- Polarity : Color band denotes cathode end
- Weight : Approximated 0.33 gram

■ Outline

DO-41(DO-204AL)



Dimensions in inches and (millimeters)

■ Maximum ratings and electrical characteristics

Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current		I_o			1.0	A
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I_{FSM}			30	A
Reverse current	$V_R = V_{RRM}$ $T_A = 25^\circ\text{C}$	I_R			5.0	uA
	$V_R = V_{RRM}$ $T_A = 125^\circ\text{C}$				100	
Diode junction capacitance	f=1MHz and applied 4V DC reverse voltage	C_j		20		pF
Storage temperature		T_{STG}	-55		+150	°C

Symbol	Marking code	Max. repetitive peak reverse voltage V_{RRM} (V)	Max. RMS voltage V_{RMS} (V)	Max. DC blocking voltage V_R (V)	Max. forward voltage @1A, $T_A = 25^\circ\text{C}$ V_F (V)	Max. reverse recovery time(1) T_{rr} (ns)	Operating temperature T_J (°C)
UF1005	UF1005	50	35	50	1.0	50	-55 ~ +150
UF101	UF101	100	70	100			
UF102	UF102	200	140	200			
UF104	UF104	400	280	400	1.40	75	
UF106	UF106	600	420	600			
UF108	UF108	800	560	800			
UF110	UF110	1000	700	1000	1.70		

Note : 1. $I_F = 0.5A$, $I_R = 1.0A$, $I_{RRM} = 0.25A$

Rating and characteristic curves

FIG.1-TYPICAL FORWARD CHARACTERISTICS

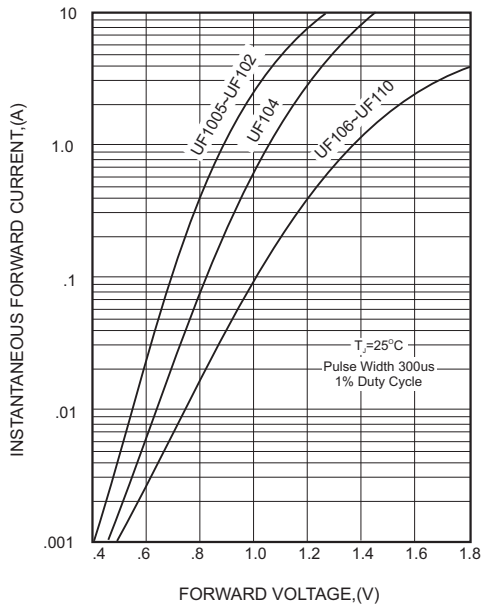


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

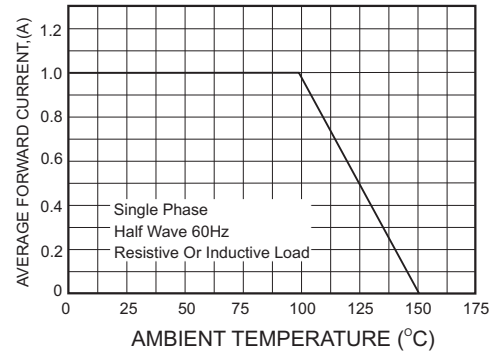
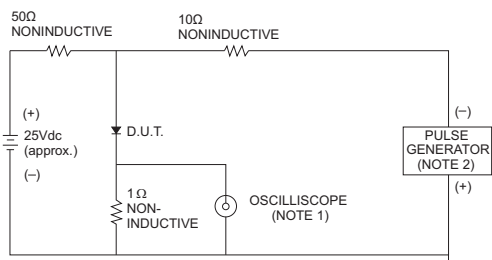


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm.22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

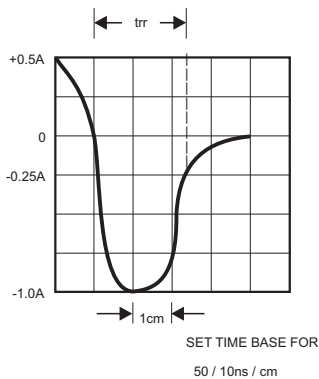


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

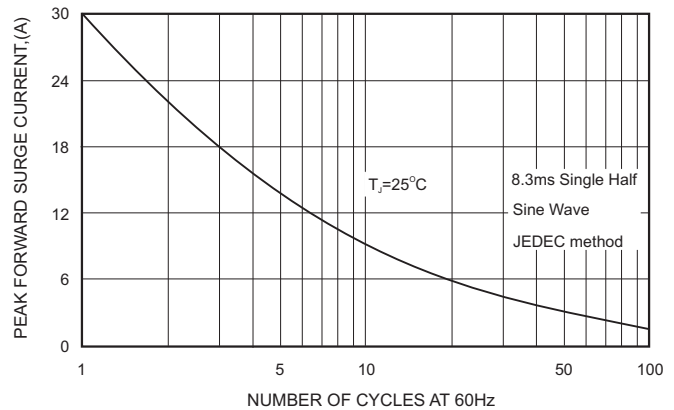
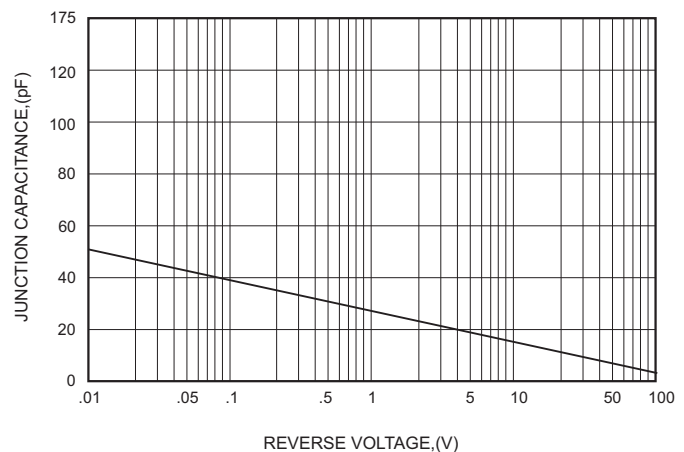


FIG.5-TYPICAL JUNCTION CAPACITANCE



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